

PNP SILICON PLANAR EPITAXIAL TRANSISTOR

2N6709



TO-237 Plastic Package

General Purpose Medium Power Amplifier

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

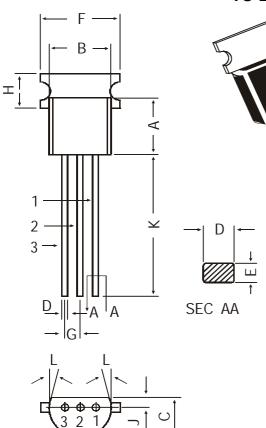
DESCRIPTION	SYMBOL	BOL VALUE	
Collector Base Voltage	V _{CBO}	80	V
Collector -Emitter Voltage	V _{CEO}	60	V
Emitter Base Voltage	V _{EBO}	5	V
Collector Current Continuous	I _C	1.5	А
Total Power Dissipation	P _D	850	mW
Operating And Storage Junction	T _i , T _{stg}	-55 to +150	°C
Temperature Range	, .		

ELECTRICAL CHARACTERISTICS (Ta=25°C Unless Specified Otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Collector Emitter Voltage	V _{CEO}	I _C =10mA, I _B =0	60		V
Collector Base Voltage	V _{CBO}	I _C =100μA, I _E =0	80		V
Emitter-Base Voltage	V_{EBO}	I _E =10μA, I _C =0	5		V
Collector Cut off Current	I _{CBO}	V _{CB} =80V, I _E =0		0.1	μΑ
Emitter Cut off Current	I _{EBO}	$V_{EB}=4V$, $I_{C}=0$		0.1	μΑ
DC Current Gain	h _{FE}	I _C =50mA,V _{CE} =2V	40		
		I _C =250mA,V _{CE} =2V	40	250	
		I _C =500mA,V _{CE} =2V	25		
Collector Emitter Saturation Voltage	V _{CE(sat})	I _C =500mA,I _B =50mA		0.5	V
		I _C =1A,I _B =100mA		1	V
Transition Frequency	f _T	V_{CE} =10V, I _C =50mA,	50		MHz

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	DIM	MIN.	MAX.	
	А	4.32	5.33	
IM.	В	4.45	5.20	
	С	3.18	4.19	
	D	0.41	0.55	
	Ε	0.35	0.50	
	F		5.40	
in n	G	1.14	1.40	
SUC	Н		2.54	
nsic	К	12.70	—	
All diminsions in mm.	L	5 DEG		
All	J	1.14	1.53	

PIN CONFIGURATION

1. BASE

2. COLLECTOR

3. EMITTER

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-237 Bulk TO-237 T&A	1K/polybag 2K/ammo box	240 gm/1K pcs 725 gm/2K pcs	3" x 7.5" x 7.5" 12.5" x 8" x 1.8"		17" x 15" x 13.5" 17" x 15" x 13.5"	80K 32K	26.2 kgs 13.8 kgs

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Disclaimer

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Data Sheet